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Ultrafast Rectifier, 8 A FRED Pt[®]



2L TO-220 FullPAK

PRIMARY CHARACTERISTICS					
I _{F(AV)}	8 A				
V _R	600 V				
V _F at I _F	0.84 V				
t _{rr} (typ.)	65 ns				
T _J max.	175 °C				
Package	2L TO-220 FullPAK				
Circuit configuration	Single				

FEATURES

- State of the art low forward voltage drop
- · Ultrafast recovery time
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- True 2 pin package
- Designed and qualified according to JEDEC®-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

State of the art, ultralow V_F, soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC-DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V _{RRM}		600	V
Average rectified forward current in DC	I _{F(AV)}	T _C = 134 °C	8	^
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	120	A
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. M		MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward valtage	V	I _F = 8 A	-	0.97	1.07	V
Forward voltage	V _F	I _F = 8 A, T _J = 150 °C	-	0.84	0.90	
Deverse lectrose ourrent		$V_{R} = V_{R}$ rated	-	0.01	9	
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	5	50	μA
Junction capacitance	C _T	V _R = 600 V - 6 -		pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8 -		nH		

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \ dI_F/dt = 100$) A/µs, V _R = 30 V	-	65	100)	
Reverse recovery time	+	$I_F = 8 \text{ A}, \ dI_F/dt = 100$	-	150	250			
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 8 A, dI _F /dt = 200 A/μs, V _R = 390 V	-	180	-	ns	
		T _J = 125 °C		-	240	-		
Pools receivers ourrent		T _J = 25 °C		-	15	-	А	
Peak recovery current	IRRM	T _J = 125 °C		-	19	-	A	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	1500	-	nC	
	Qrr	T _J = 125 °C		-	2400	-	no	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction-to-case	R _{thJC}		-	4.6	5.5		
Thermal resistance, junction-to-ambient	R _{thJA}	R _{thJA} Typical socket mount		-	70	°C/W	
Typical thermal resistance, case-to-heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-		
Weight			-	2	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style 2L TO-220 FullPAK	ETL0806FP				

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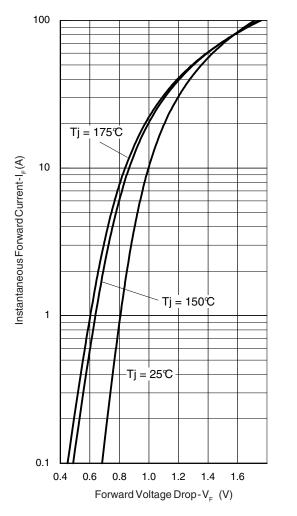


Fig. 1 - Typical Forward Voltage Drop Characteristics

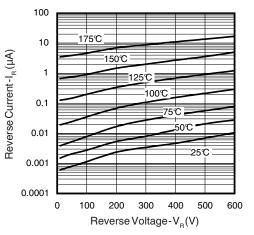


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

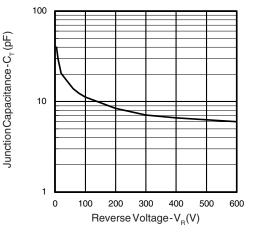
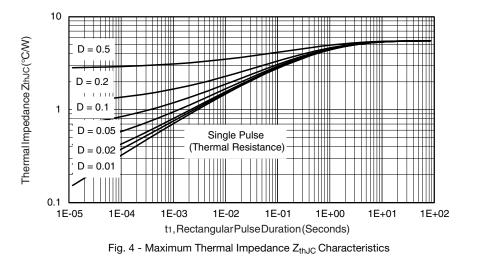


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



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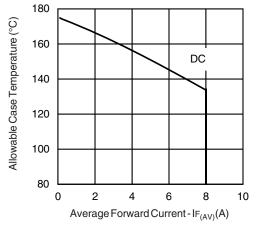


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

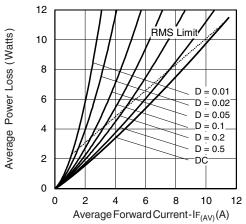
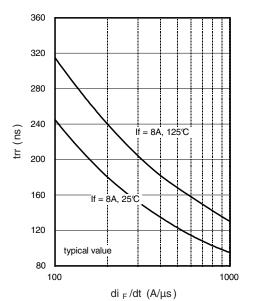
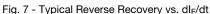


Fig. 6 - Forward Power Loss Characteristics



VS-ETL0806FP-M3

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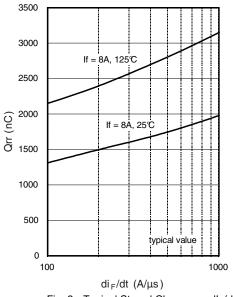
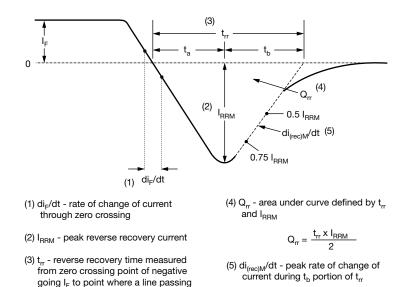


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	VS-	E	Т	L	08	06	FP	-M3
	1	2	3	4	5	6	7	8
	1	- Visl	nay Sen	nicondu	ctors pr	oduct		
	2	- Circ	cuit con	figuratio	n:			
		E =	single					
	3	• T=	TO-220)				
	4	- L=	hyperfa	st recov	very time	е		
	5	- Cur	rent co	de: 08 =	8 A			
	6	- Vol	tage co	de: 06 =	600 V			
	7	FP	= 2L TO	-220 Fu	IIPAK			
	8 -	- Env	ironmer	ntal digit	:			
		-M3	3 = halo	gen-free	e, RoHS	-compli	iant, and	d termir

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-ETL0806FP-M3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96157					
Part marking information	www.vishay.com/doc?95392				

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